

# 2SC2613

Silicon NPN Triple Diffused

# HITACHI

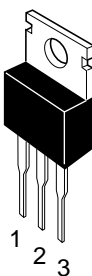
ADE-208-886 (Z)  
1st. Edition  
Sep. 2000

## Application

High voltage, high speed and high power switching

## Outline

TO-220AB



1. Base
2. Collector (Flange)
3. Emitter

## Absolute Maximum Ratings ( $T_a = 25^{\circ}\text{C}$ )

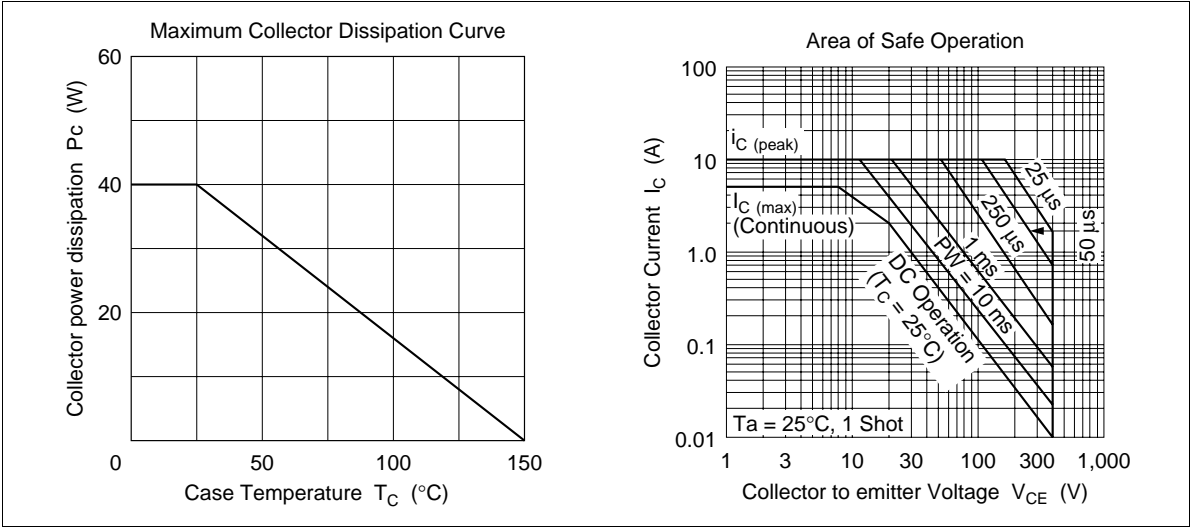
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{\text{CBO}}$	500	V
Collector to emitter voltage	$V_{\text{CEO}}$	400	V
Emitter to base voltage	$V_{\text{EBO}}$	7	V
Collector current	$I_{\text{C}}$	5	A
Collector peak current	$I_{\text{C(peak)}}$	10	A
Base current	$I_{\text{B}}$	2.5	A
Collector power dissipation	$P_{\text{C}}^{*1}$	40	W
Junction temperature	$T_{\text{j}}$	150	$^{\circ}\text{C}$
Storage temperature	$T_{\text{stg}}$	-55 to +150	$^{\circ}\text{C}$

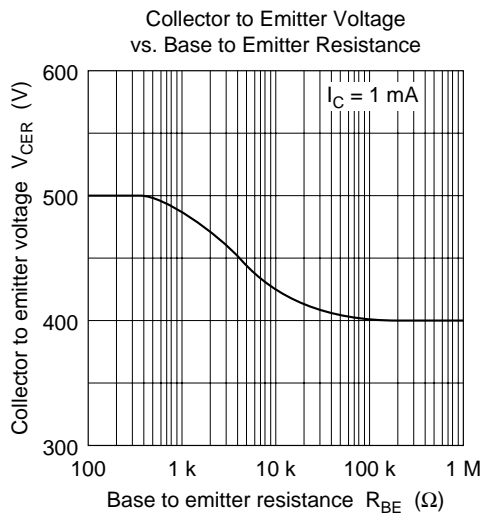
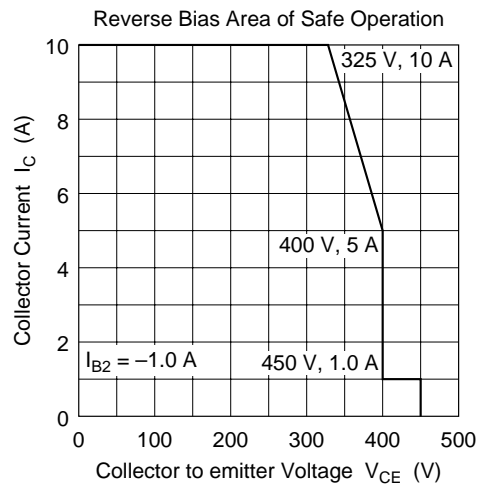
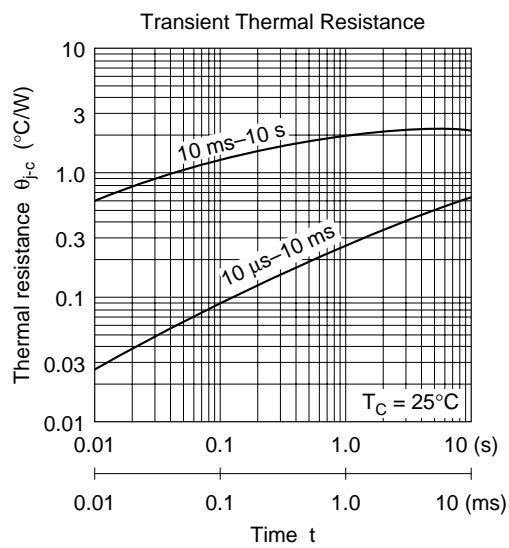
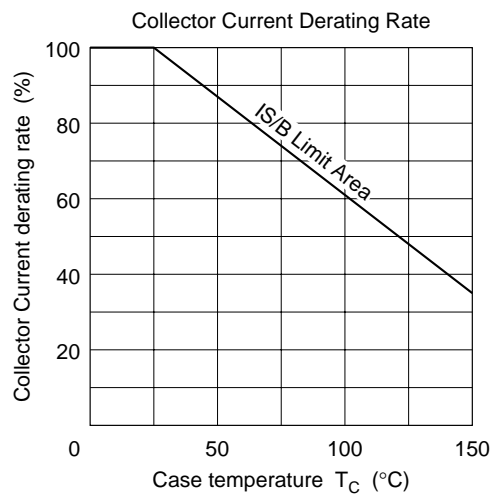
Note: 1. Value at  $T_{\text{C}} = 25^{\circ}\text{C}$ .

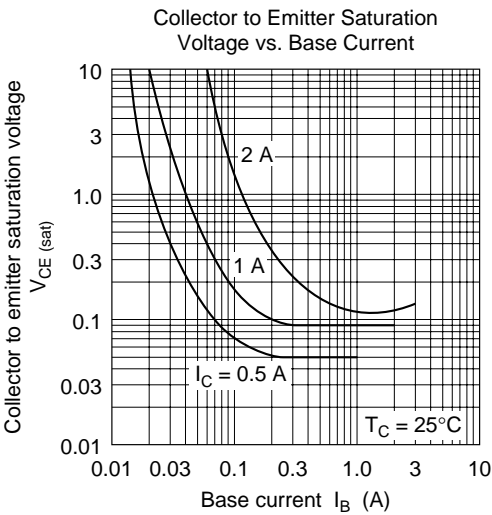
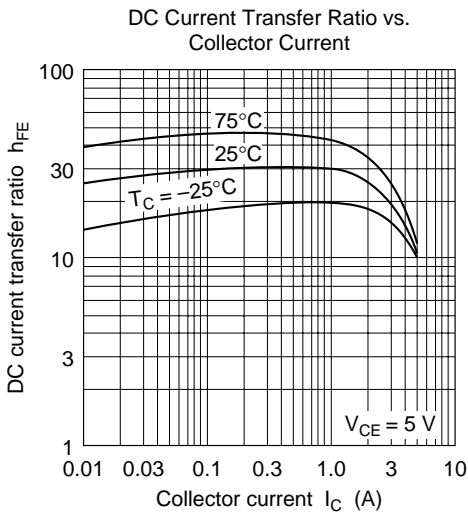
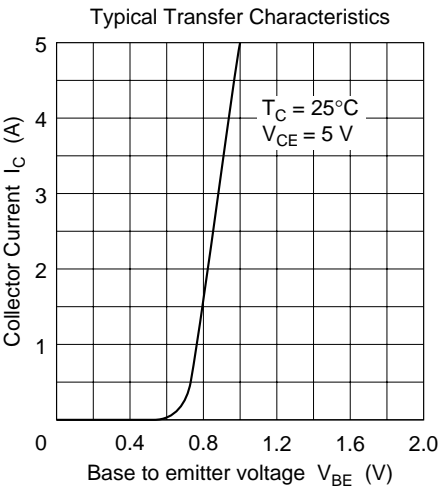
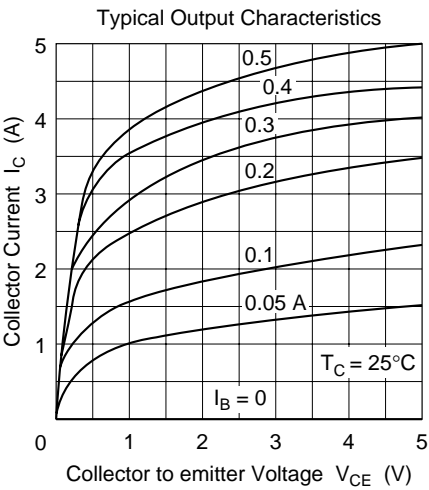
Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to emitter sustain voltage	$V_{CEO(sus)}$	400	—	—	V	$I_C = 0.2\text{ A}$ , $R_{BE} = \infty$ , $L = 100\text{ mH}$
	$V_{CEX(sus)}$	400	—	—	V	$I_C = 5\text{ A}$ , $I_{B1} = -I_{B2} = 1\text{ A}$ $V_{BE} = -5\text{ V}$ , $L = 180\text{ }\mu\text{H}$ , Clamped
Emitter to base breakdown voltage	$V_{(BR)EBO}$	7	—	—	V	$I_E = 10\text{ mA}$ , $I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	100	$\mu\text{A}$	$V_{CB} = 400\text{ V}$ , $I_E = 0$
	$I_{CEO}$	—	—	100	$\mu\text{A}$	$V_{CE} = 350\text{ V}$ , $R_{BE} = \infty$
DC current transfer ratio	$h_{FE1}$	15	—	—		$V_{CE} = 5\text{ V}$ , $I_C = 2.5\text{ A}^{*1}$
	$h_{FE2}$	7	—	—		$V_{CE} = 5\text{ V}$ , $I_C = 5\text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.0	V	$I_C = 2.5\text{ A}$ , $I_B = 0.5\text{ A}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	—	1.5	V	$I_C = 2.5\text{ A}$ , $I_B = 0.5\text{ A}^{*1}$
Turn on time	$t_{on}$	—	—	1.0	$\mu\text{s}$	$I_C = 5\text{ A}$ , $I_{B1} = -I_{B2} = 1\text{ A}$ ,
Storage time	$t_{stg}$	—	1.2	2.5	$\mu\text{s}$	$V_{CC} \cong 150\text{ V}$
Fall time	$t_f$	—	—	1.0	$\mu\text{s}$	

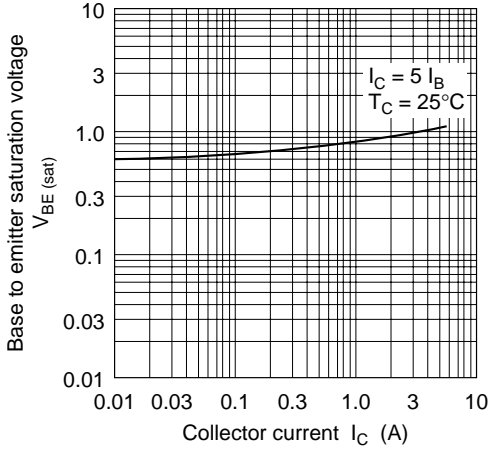
Note: 1. Pulse test.



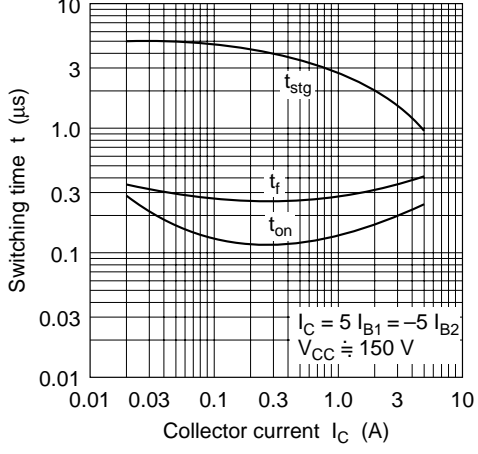




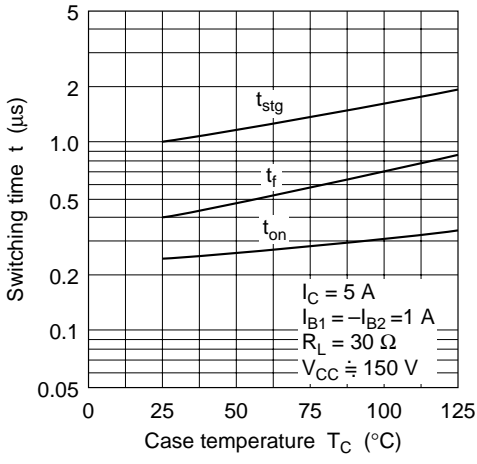
Base to Emitter Saturation Voltage  
vs. Collector Current



Switching Time vs. Collector Current

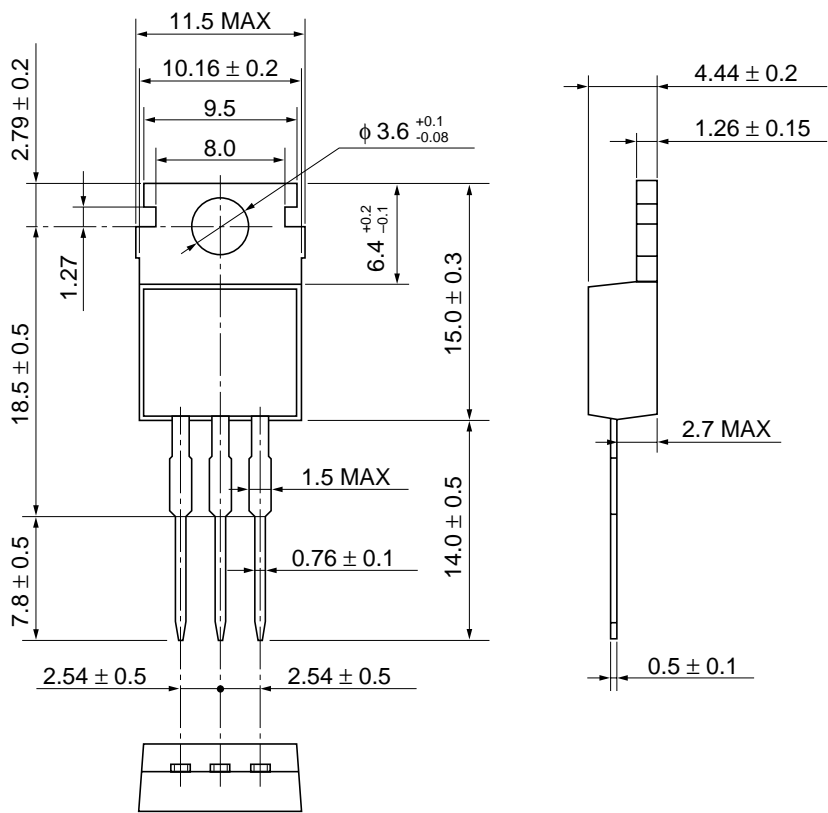


Switching Time vs. Case Temperature



Package Dimensions

Unit: mm



Hitachi Code	TO-220AB
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	1.8 g

## Cautions

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# HITACHI

## Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL	North America	: <a href="http://semiconductor.hitachi.com/">http://semiconductor.hitachi.com/</a>
	Europe	: <a href="http://www.hitachi-eu.com/hel/ecg">http://www.hitachi-eu.com/hel/ecg</a>
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## For further information write to:

Hitachi Semiconductor  
(America) Inc.  
179 East Tasman Drive,  
San Jose, CA 95134  
Tel: <1> (408) 433-1990  
Fax: <1> (408) 433-0223

Hitachi Europe GmbH  
Electronic Components Group  
Dornacher Straße 3  
D-85622 Feldkirchen, Munich  
Germany  
Tel: <49> (89) 9 9180-0  
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.  
Electronic Components Group.  
Whitebrook Park  
Lower Cookham Road  
Maidenhead  
Berkshire SL6 8YA, United Kingdom  
Tel: <44> (1628) 585000  
Fax: <44> (1628) 585160

Hitachi Asia Ltd.  
Hitachi Tower  
16 Collyer Quay #20-00,  
Singapore 049318  
Tel: <65>-538-6533/538-8577  
Fax: <65>-538-6933/538-3877  
URL: <http://www.hitachi.com.sg>

Hitachi Asia Ltd.  
(Taipei Branch Office)  
4/F, No. 167, Tun Hwa North Road,  
Hung-Kuo Building,  
Taipei (105), Taiwan  
Tel: <886>-(2)-2718-3666  
Fax: <886>-(2)-2718-8180  
Telex: 23222 HAS-TP  
URL: <http://www.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.  
Group III (Electronic Components)  
7/F., North Tower,  
World Finance Centre,  
Harbour City, Canton Road  
Tsim Sha Tsui, Kowloon,  
Hong Kong  
Tel: <852>-(2)-735-9218  
Fax: <852>-(2)-730-0281  
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